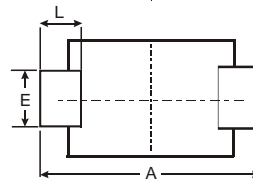
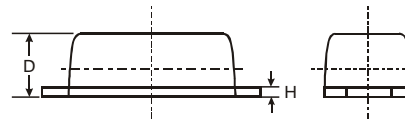
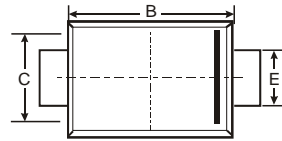
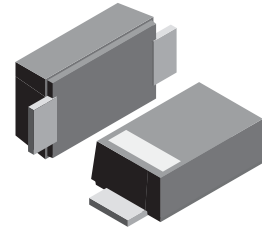


**VOLTAGE RANGE: 20 - 100V**  
**CURRENT: 2.0 A**

### Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O



SMBF			
Dim	Min	Max	Typ
A	5.45	5.55	5.50
B	4.27	4.33	4.30
C	3.57	3.63	3.60
D	1.32	1.38	1.35
E	1.96	2.00	1.98
H	0.019	0.021	0.20
L	0.73	0.77	0.75
All Dimensions in mm			

### Mechanical Data

- Case: SMBF, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.0018 ounces, 0.05grams



### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SS22F	SS23F	SS24F	SS25F	SS26F	SS28F	SS210F	Unit
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	V
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	V
Maximum average forward rectified current at T <sub>L</sub> (see fig.1)	I <sub>(AV)</sub>	2.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	50.0							A
Maximum instantaneous forward voltage at 2.0A	V <sub>F</sub>	0.55		0.70		0.85		V	
Maximum DC reverse current at rated DC blocking voltage <small>T<sub>A</sub>=25°C</small> <small>T<sub>A</sub>=100°C</small>	I <sub>R</sub>	0.5			10			mA	
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	220		180		pF			
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>	75.0							°C/W
Operating junction temperature range	T <sub>J</sub>	-65 to +125			-65 to +150			°C	
Storage temperature range	T <sub>STG</sub>	-65 to +150							°C

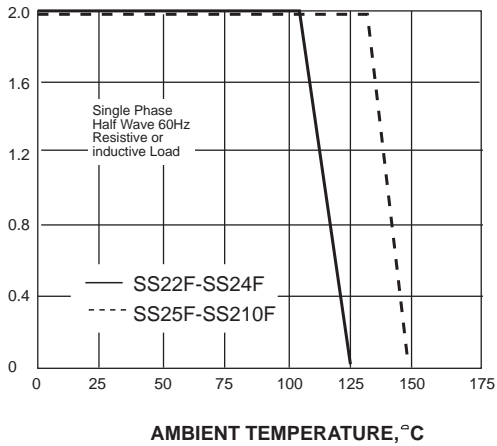
**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

## RATINGS AND CHARACTERISTIC CURVES SS22F THRU SS210F

AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

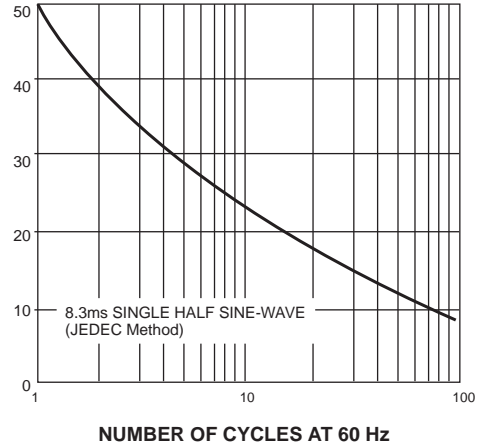
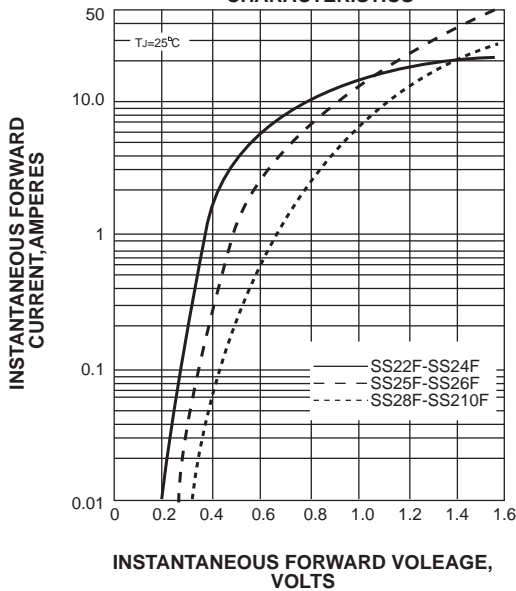


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

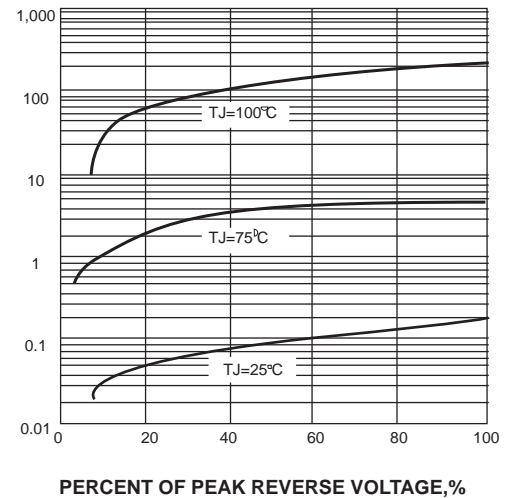
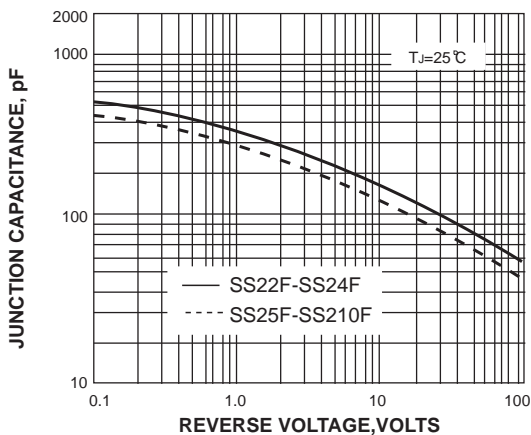


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

